NSN 5961-01-029-1014

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a contractor drawing, original equipment manufacturer drawing, etc.;

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Inclosure Ma	iterial:
Metal	
Overall Leng	th:
Between 0.17	'0 inches and 0.210 inches
Terminal Ler	ngth:
0.500 inches	
Overall Diam	eter:
Between 0.20	9 inches and 0.230 inches
Internal Con	figuration:
Field effect	
Electrode Inf	ernally-electrically Connected To Case:
Collector	
Mounting Me	ethod:
Terminal	
Terminal Cir	cle Diameter:
0.110 inches	
Features Pro	vided:
Hermetically	sealed case
Semiconduc	tor Material:
Silicon	
Voltage Rati	ng In Volts Per Characteristic:
-30.0 on-stat	e drain to source voltage
Current Rati	ng Per Characteristic:
10.00 milliam	peres gate current
Power Rating	g Per Characteristic:
1.8 watts tota	al power dissipation
Maximum Oj	perating Tempurature Per Measurement Point:
200.0 degree	s celsius ambient air
Test Data Do	ocument:
10001-28880	21 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment
excludes any	specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Typ	be And Quantity:
3 uninsulated	wire lead
Shelf Life:	
N/a	
Unit Of Meas	sure:
Demilitarizat	ion:
No	
Fiig:	
A110a0	